# New Jersey Semi-Conductor Products, Inc.

20 STERN AVE. SPRINGFIELD, NEW JERSEY 07081 U.S.A.

TELEPHONE: (973) 376-2922

(212) 227-6005

FAX: (973) 376-8960

# Fast soft-recovery controlled avalanche rectifiers

## **BYW95** series

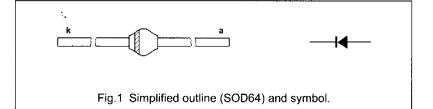
#### **FEATURES**

- · Glass passivated
- High maximum operating temperature
- · Low leakage current
- · Excellent stability
- Guaranteed avalanche energy absorption capability
- · Available in ammo-pack
- Also available with preformed leads for easy insertion.

#### DESCRIPTION

Rugged glass SOD64 package, using a high temperature alloyed

construction. This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	repetitive peak reverse voltage				
	BYW95A		_	200	V
	BYW95B		_	400	V
	BYW95C		_	600	V
V <sub>R</sub>	continuous reverse voltage				
	BYW95A			200	V
	BYW95B		_	400	V
	BYW95C		_	600	V
I <sub>F(AV)</sub>	average forward current	T <sub>tp</sub> = 60 °C; lead length = 10 mm see Fig.2; averaged over any 20 ms period; see also Fig.6	_	3.00	А
		T <sub>amb</sub> = 65 °C; PCB mounting (see Fig.11); see Fig.3; averaged over any 20 ms period; see also Fig.6	_	1.25	A
I <sub>FRM</sub>	repetitive peak forward current	T <sub>tp</sub> = 60 °C; see Fig.4	_	30	Α
		T <sub>amb</sub> = 65 °C; see Fig.5	_	13	Α
I <sub>FSM</sub>	non-repetitive peak forward current	t = 10 ms half sine wave; T <sub>j</sub> = T <sub>j max</sub> prior to surge; V <sub>R</sub> = V <sub>RRMmax</sub>	_	70	А
E <sub>RSM</sub>	non-repetitive peak reverse avalanche energy	L = 120 mH; $T_j = T_{j \text{ max}}$ prior to surge; inductive load switched off	_	10	mJ
T <sub>stg</sub>	storage temperature		-65	+175	°C
Tj	junction temperature	see Fig.7	-65	+175	°C

NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

**Quality Semi-Conductors** 

Download from alldatasheet.com

# Fast soft-recovery controlled avalanche rectifiers

BYW95 series

### **ELECTRICAL CHARACTERISTICS**

T<sub>j</sub> = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	forward voltage	$I_F = 5 \text{ A}$ ; $T_j = T_{j \text{ max}}$ ; see Fig.8	_	_	1.25	V
		I <sub>F</sub> = 5 A; see Fig.8	AA.MA.	-	1.50	V
V <sub>(BR)R</sub>	reverse avalanche breakdown voltage	I <sub>R</sub> = 0.1 mA				
	BYW95A		300	-	-	V
	BYW95B		500	_	_	V
	BYW95C		700	_	_	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = V <sub>RRMmax</sub> ; see Fig.9	-	-	1	μА
		V <sub>R</sub> = V <sub>RRMmax</sub> ; T <sub>j</sub> = 165 °C; see Fig.9	_	_	150	μА
t <sub>rr</sub>	reverse recovery time	when switched from $I_F = 0.5$ A to $I_R = 1$ A; measured at $I_R = 0.25$ A; see Fig.12	_	-	250	ns
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0 V; see Fig.10	-	85	-	pF
$\left  \frac{dI_{R}}{dt} \right $	maximum slope of reverse recovery current	when switched from $I_F$ = 1 A to $V_R \ge 30$ V and $dI_F/dt$ = $-1$ A/ $\mu$ s; see Fig.13	_	_	7	A/μs

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-tp</sub>	thermal resistance from junction to tie-point	lead length = 10 mm	25	K/W
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	75	K/W